

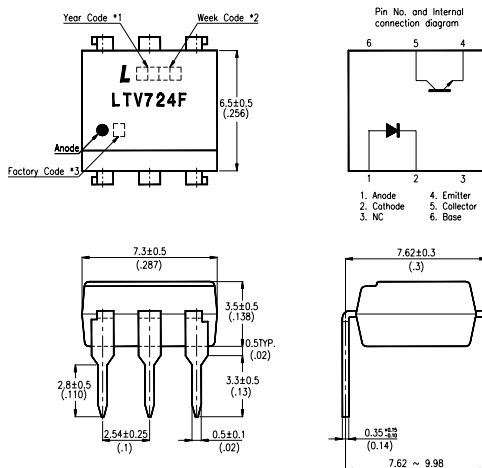
Features

- High isolation voltage between input and output
- High input current (I_F : MAX. 150 mA)
- Low collector dark current
(I_{CEO} : MAX. 10^{-7} A at $V_{CE} = 20V$)
- Current transfer ratio
(CTR : 20% ~ 80% at $I_F = 100mA$, $V_{CE} = 2V$)
- High input-output isolation voltage
($V_{ISO} = 5,000V_{rms}$)
- Response time
(t_r : TYP. 4 μs at $V_{CE} = 5V$, $I_C = 2mA$, $R_L = 100 \Omega$)
- UL approved (No. E113898)
- CSA approved (No. CA91533-1)
- FIMKO approved (No. 202944)
- NEMKO approved (No. P98101738)
- DEMKO approved (No. 307923)
- SEMKO approved (No. 9833171/01)
- VDE approved (No. 094722)
- Options Available :
 - Leads with 0.4" (10.16mm) Spacing (M Type)
 - Lead Bends for Surface Mounting (S Type)
 - Tape and Reel of Type I for SMD (Add "-TA" Suffix)
 - Tape and Reel of Type II for SMD (Add "-TA1" Suffix)
 - VDE 0884 Approvals (Add "-V" Suffix)

Applications

1. Telephone sets
2. I/O interfaces for microcomputer
3. System appliances, measuring instruments
4. Signal transmission between circuits of different potentials and impedances

Package Dimensions



Notes :

1. Year date code.
2. 2-digit work week.
3. Factory code shall be marked
(Z : Taiwan, Y : Thailand).
4. All dimensions are in millimeters (inches).
5. Tolerance is $\pm 0.25mm$ (.010") unless otherwise noted.
6. Specifications are subject to change without notice.

Ordering Information

Part Number	Package	Safety Standard Approval	Application part number
LTV-724F LTV-724FM LTV-724FS LTV-724FS-TA LTV-724FS-TA1	6-pin DIP 6-pin (leads with 0.4" spacing) 6-pin (lead bends for surface mount) 6-pin (tape and reel packaging of type I) 6-pin (tape and reel packaging of type II)	• UL approved • CSA approved • FIMKO approved • NEMKO approved • DEMKO approved • SEMKO approved	LTV - 724F
LTV724F-V LTV724FM-V LTV724FS-V LTV724FSTA-V LTV724FSTA1-V	6-pin DIP 6-pin (leads with 0.4" spacing) 6-pin (lead bends for surface mount) 6-pin (tape and reel packaging of type I) 6-pin (tape and reel packaging of type II)	• VDE approved	LTV - 724F

Ratings and Characteristics

Absolute Maximum Ratings

(Ta=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward Current	I _F	150	mA
	Reverse Voltage	V _R	6	V
	Power Dissipation	P	230	mW
Output	Collector-Emitter Voltage	V _{CEO}	35	V
	Emitter-Collector Voltage	V _{ECO}	6	V
	Collector Current	I _C	80	mA
	Collector Power Dissipation	P _C	160	mW
Total Power Dissipation		P _{tot}	320	mW
*1. Isolation Voltage		V _{iso}	5,000	V _{rms}
Operating Temperature		T _{opr}	-25~+100	°C
Storage Temperature		T _{stg}	-55~+125	°C
*2. Soldering Temperature		T _{sol}	260	°C

*1. AC for 1 minute, R.H. = 40 ~ 60%

Isolation voltage shall be measured using the following method.

- (1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.

*2. For 10 seconds

Electrical / Optical Characteristics

(Ta=25°C)

	Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input	Forward Voltage	V _F	—	1.4	1.7	V	I _F =100mA
	Reverse Current	I _R	—	—	10	μA	V _R =4V
	Terminal Capacitance	C _t	—	30	250	pF	V=0, f=1KHz
Output	Collector Dark Current	I _{CEO}	—	—	10 ⁻⁷	A	V _{CE} =20V, I _F =0
	Collector-Emitter Breakdown Voltage	BV _{CEO}	35	—	—	V	I _C =0.1mA I _F =0
	Emitter-Collector Breakdown Voltage	BV _{ECO}	6	—	—	V	I _E =10 μA I _F =0
	Collector Current	I _C	20	—	80	mA	I _F =100mA
Transfer Characteristics	*1 Current Transfer Ratio	CTR	20	—	80	%	V _{CE} =2V
	Collector-emitter Saturation Voltage	V _{CE(sat)}	—	0.1	0.2	V	I _F =100mA I _C =1mA
	Isolation Resistance	R _{iso}	5 × 10 ¹⁰	1 × 10 ¹¹	—	Ω	DC500V 40~60%R.H.
	Floating Capacitance	C _f	—	0.6	1	pF	V=0, f=1MHz
	Cut-off Frequency	f _c	—	100	—	kHz	V _{CE} =5V, I _C =2mA R _L =100 Ω, -3dB
	Response Time (Rise)	t _r	—	4	18	μs	V _{CE} =5V, I _C =2mA R _L =100 Ω
	Response Time (Fall)	t _f	—	3	18	μs	

*1 CTR= $\frac{I_C}{I_F} \times 100\%$

Typical Electrical/Optical Characteristic Curves
(25°C Ambient Temperature Unless Otherwise Noted)

Fig.1 Forward Current vs. Ambient Temperature

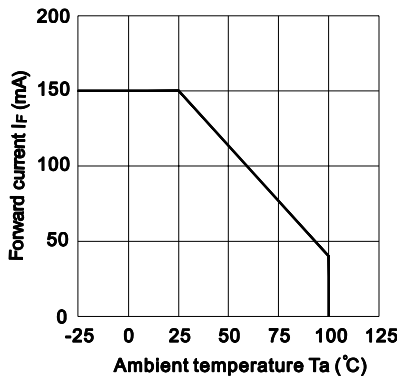


Fig.2 Collector Power Dissipation vs. Ambient Temperature

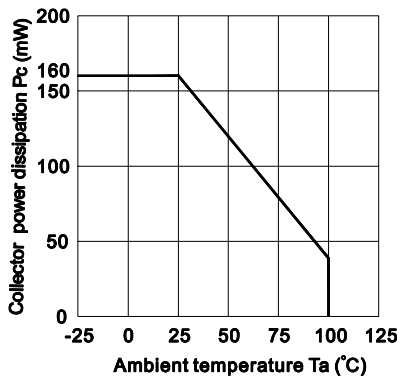


Fig.3 Collector Current vs. Collector-emitter Voltage

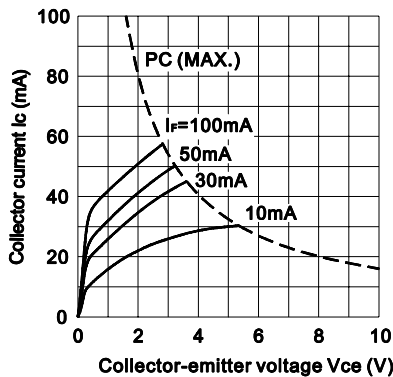


Fig.4 Forward Current vs. Forward Voltage

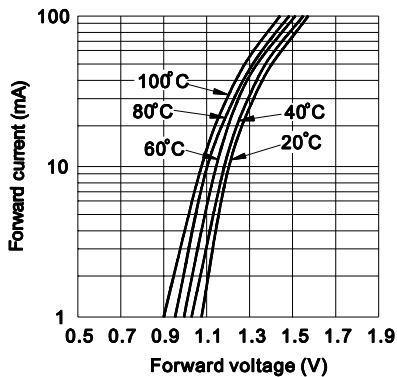


Fig.5 Current Transfer Ratio vs. Forward Current

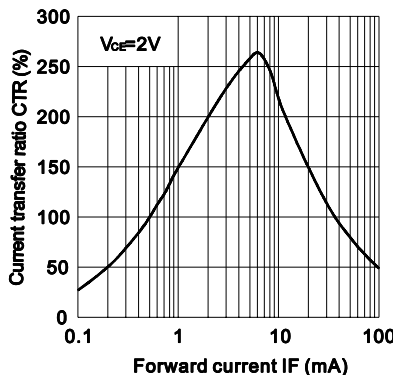
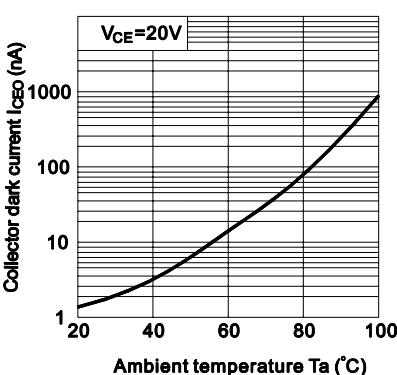


Fig.6 Collector Dark Current vs. Ambient Temperature



**Fig.7 Response Time vs.
Load Resistance**

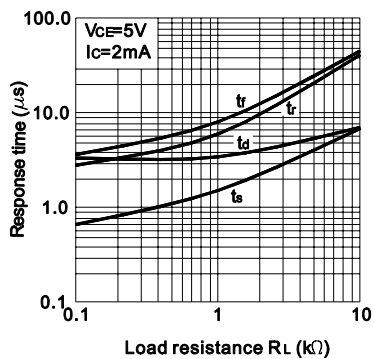
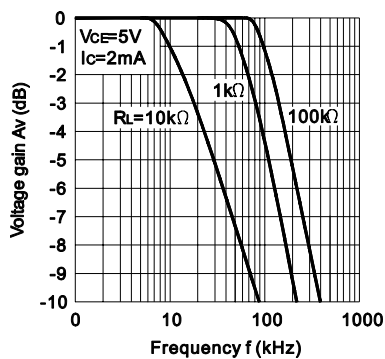
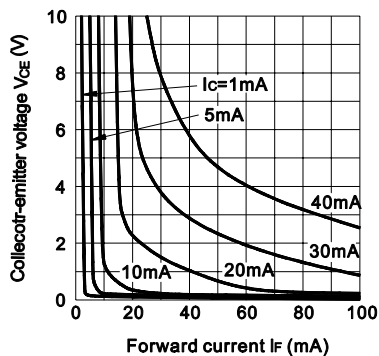


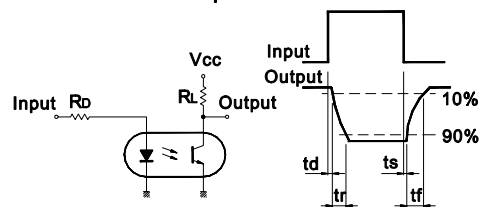
Fig.8 Frequency Response



**Fig.9 Collector-emitter Voltage vs.
Ambient Temperature**



Test Circuit for Response Time



Test Circuit for Frequency Response

